FAIRCHILD SEMICONDUCTOR®

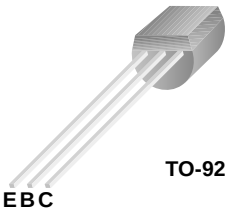
October 2011

2N3904 / MMBT3904 / PZT3904
NPN General Purpose Amplifier

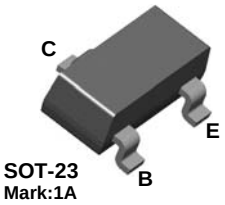
Features

- This device is designed as a general purpose amplifier and switch.
- The useful dynamic range extends to 100 mA as a switch and to 100 MHz as an amplifier.

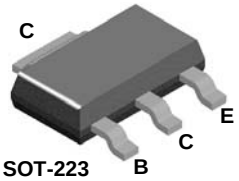
2N3904



MMBT3904



PZT3904



Absolute Maximum Ratings* T_a = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CEO}	Collector-Emitter Voltage	40	V
V_{CBO}	Collector-Base Voltage	60	V
V_{EBO}	Emitter-Base Voltage	6.0	V
I_C	Collector Current - Continuous	200	mA
T_J, T_{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics T_a = 25°C unless otherwise noted

Symbol	Parameter	Max.			Units
		2N3904	*MMBT3904	**PZT3904	
P_D	Total Device Dissipation Derate above 25°C	625 5.0	350 2.8	1,000 8.0	mW mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3			°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	357	125	°C/W

* Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06".

** Device mounted on FR-4 PCB 36 mm X 18 mm X 1.5 mm; mounting pad for the collector lead min. 6 cm^2.

Electrical Characteristics T_a = 25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
OFF CHARACTERISTICS					
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	I_C = 1.0mA, I_B = 0	40		V
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	I_C = 10μA, I_E = 0	60		V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	I_E = 10μA, I_C = 0	6.0		V
I_{BL}	Base Cutoff Current	V_{CE} = 30V, V_{EB} = 3V		50	nA
I_{CEX}	Collector Cutoff Current	V_{CE} = 30V, V_{EB} = 3V		50	nA
ON CHARACTERISTICS*					
h_{FE}	DC Current Gain	I_C = 0.1mA, V_{CE} = 1.0V I_C = 1.0mA, V_{CE} = 1.0V I_C = 10mA, V_{CE} = 1.0V I_C = 50mA, V_{CE} = 1.0V I_C = 100mA, V_{CE} = 1.0V	40 70 100 60 30	 300 	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	I_C = 10mA, I_B = 1.0mA I_C = 50mA, I_B = 5.0mA		0.2 0.3	V V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	I_C = 10mA, I_B = 1.0mA I_C = 50mA, I_B = 5.0mA	0.65	0.85 0.95	V V
SMALL SIGNAL CHARACTERISTICS					
f_T	Current Gain - Bandwidth Product	I_C = 10mA, V_{CE} = 20V, f = 100MHz	300		MHz
C_{obo}	Output Capacitance	V_{CB} = 5.0V, I_E = 0, f = 1.0MHz		4.0	pF
C_{ibo}	Input Capacitance	V_{EB} = 0.5V, I_C = 0, f = 1.0MHz		8.0	pF
NF	Noise Figure	I_C = 100μA, V_{CE} = 5.0V, R_S = 1.0kΩ, f = 10Hz to 15.7kHz		5.0	dB
SWITCHING CHARACTERISTICS					
t_d	Delay Time	V_{CC} = 3.0V, V_{BE} = 0.5V I_C = 10mA, I_{B1} = 1.0mA		35	ns
t_r	Rise Time			35	ns
t_s	Storage Time	V_{CC} = 3.0V, I_C = 10mA, I_{B1} = I_{B2} = 1.0mA		200	ns
t_f	Fall Time			50	ns

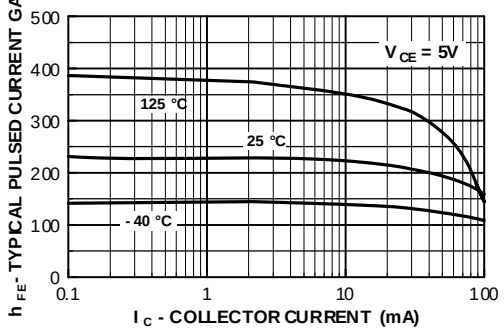
* Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2.0%

Ordering Information

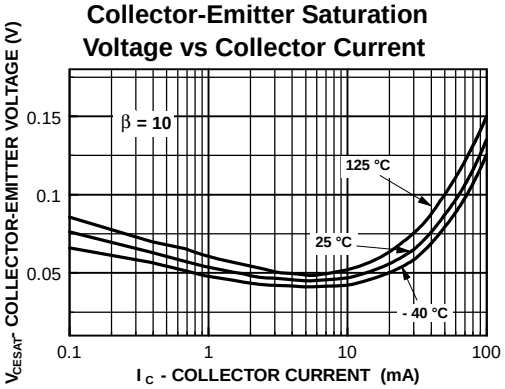
Part Number	Marking	Package	Packing Method	Pack Qty
2N3904BU	2N3904	TO-92	BULK	10000
2N3904TA	2N3904	TO-92	AMMO	2000
2N3904TAR	2N3904	TO-92	AMMO	2000
2N3904TF	2N3904	TO-92	TAPE REEL	2000
2N3904TFR	2N3904	TO-92	TAPE REEL	2000
MMBT3904	1A	SOT-23	TAPE REEL	3000
MMBT3904_D87Z	1A	SOT-23	TAPE REEL	10000
PZT3904	3904	SOT-223	TAPE REEL	2500

Typical Performance Characteristics

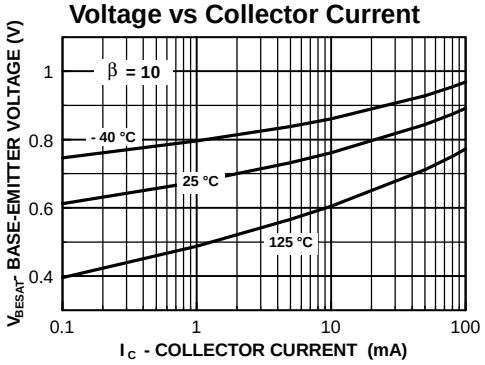
Typical Pulsed Current Gain vs Collector Current



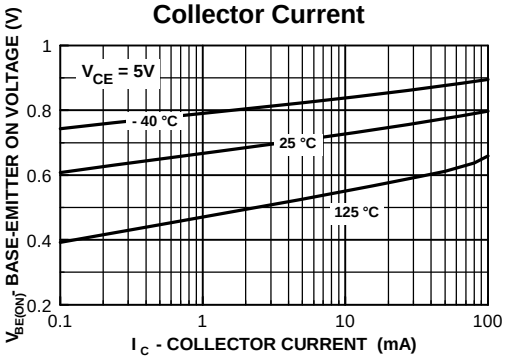
Collector-Emitter Saturation Voltage vs Collector Current



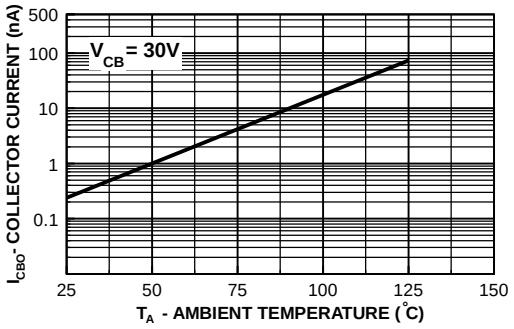
Base-Emitter Saturation Voltage vs Collector Current



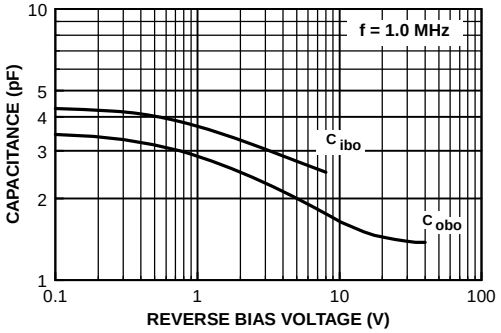
Base-Emitter ON Voltage vs Collector Current



Collector-Cutoff Current vs Ambient Temperature

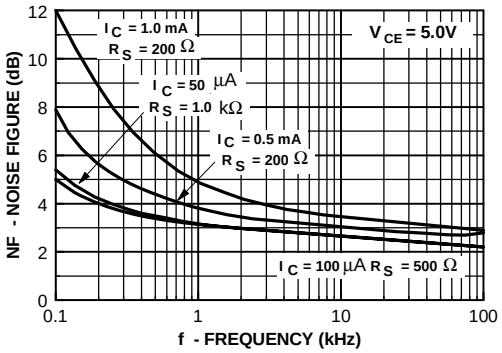


Capacitance vs Reverse Bias Voltage

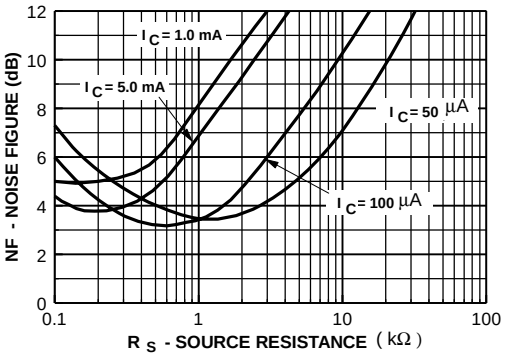


Typical Performance Characteristics (continued)

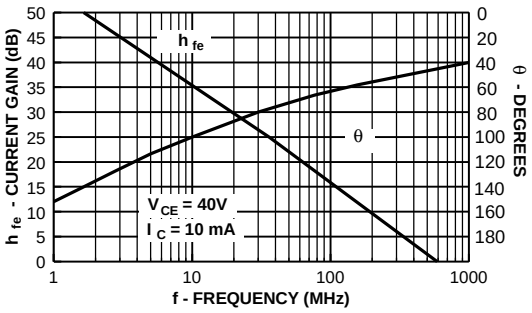
Noise Figure vs Frequency



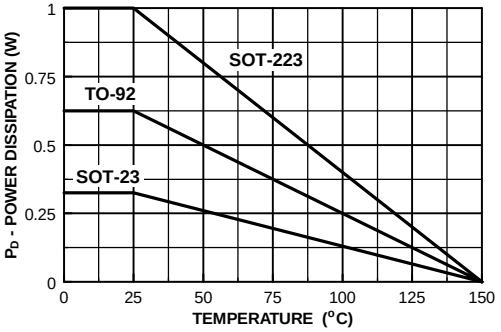
Noise Figure vs Source Resistance



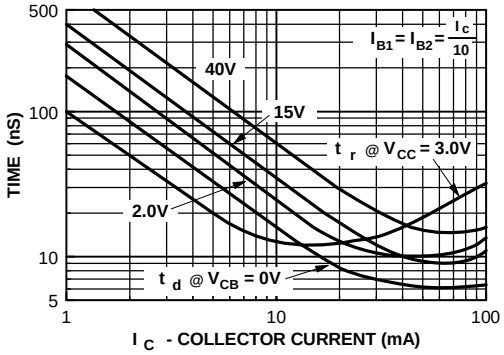
Current Gain and Phase Angle vs Frequency



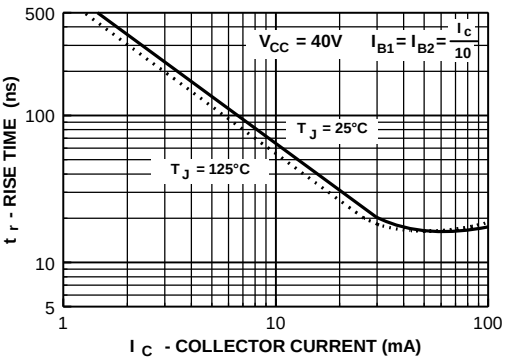
Power Dissipation vs Ambient Temperature



Turn-On Time vs Collector Current

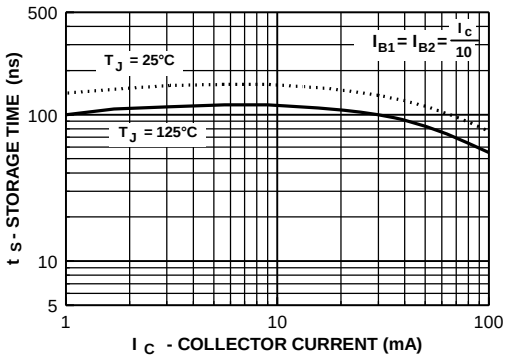


Rise Time vs Collector Current

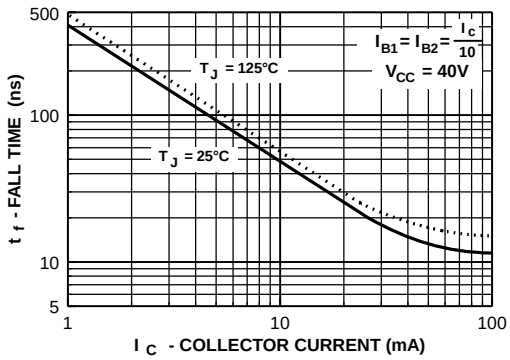


Typical Performance Characteristics (continued)

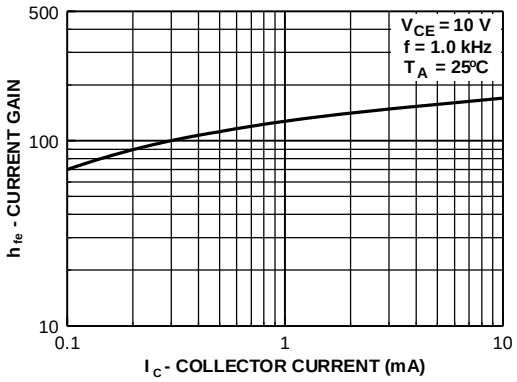
Storage Time vs Collector Current



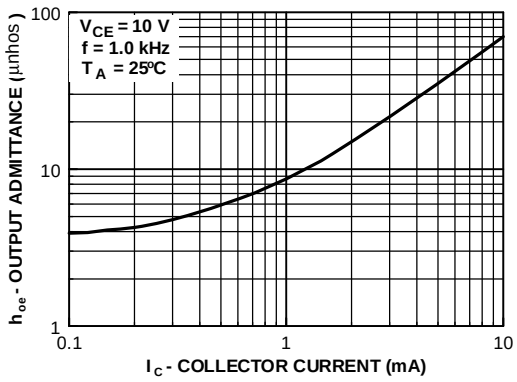
Fall Time vs Collector Current



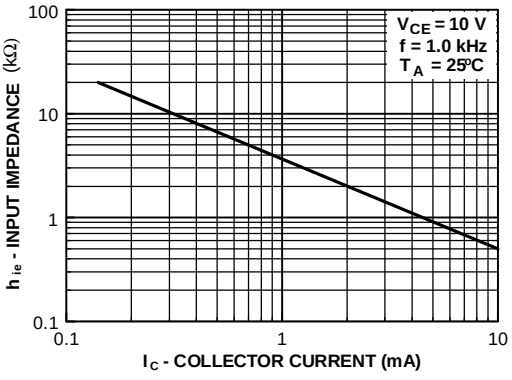
Current Gain



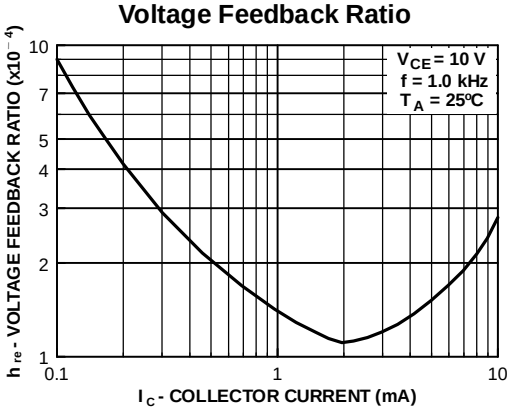
Output Admittance



Input Impedance



Voltage Feedback Ratio



Test Circuits

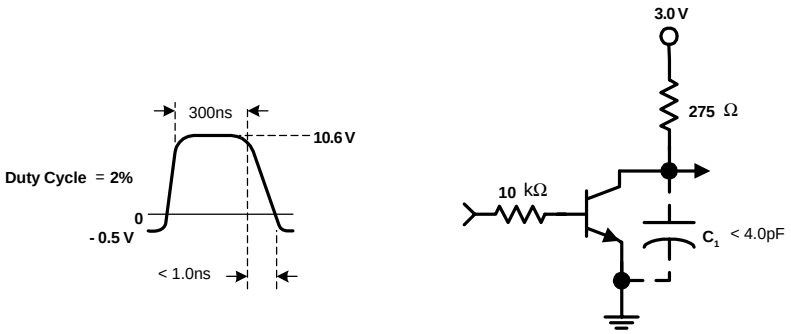


FIGURE 1: Delay and Rise Time Equivalent Test Circuit

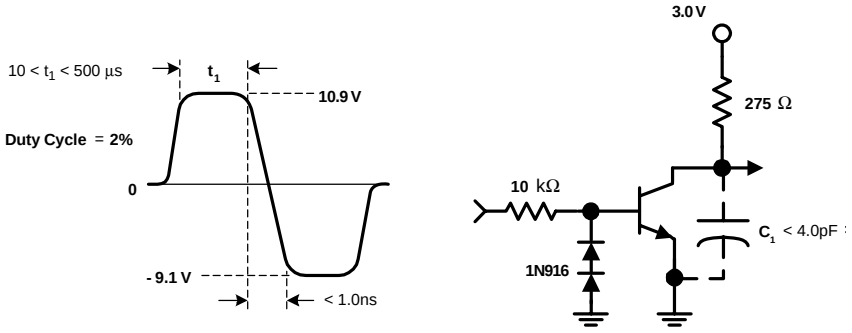


FIGURE 2: Storage and Fall Time Equivalent Test Circuit

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Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

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